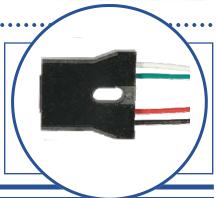
Reflective Line Reader Sensor Type OPB739RWZ



Features:

- Focused for maximum sensitivity
- **Phototransistor Output**
- 650nm Visible Red LED to optimize detection of dye based inks
- Low-cost plastic housing
- 24" minimum 26AWG wire leads
- Optimal operating distance range 0.015" [.38mm] to 0.045" [1.14mm]



Description:

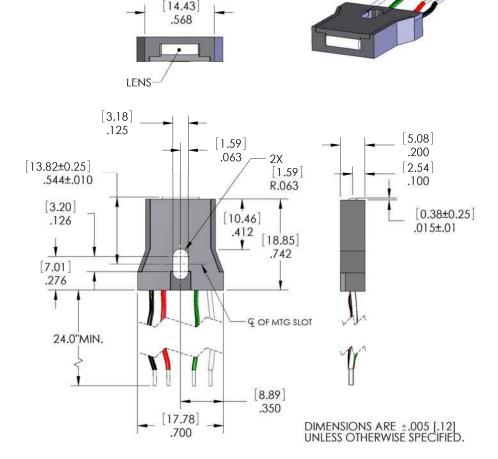
The OPB739RWZ is a reflective line reader sensor. The sensor utilizes a visible red (650nm) LED and an NPN silicon phototransistor mounted side by side on converging optical axes in a black plastic housing. The converging light beam makes this sensor capable of detecting line widths as small as 0.004" [0.1mm] at the optimum distance of 0.030" [0.76mm] from the target. The red LED maximizes the reflected signal contrast of black lines on white backgrounds. Recommended line spacing is .050" minimum.

This sensor can be used with Optek's OCB100CZ auto calibration module to reduce variability from sensor to sensor and to achieve a digital output.

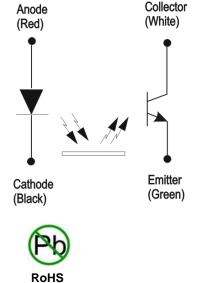
Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Line Reading
 Low Resolution Bar Code Sensing
- Paper edge detection
- Mark detection
- Reflective Optical Encoders







Reflective Line Reader Sensor Type OPB739RWZ



Storage and Operating Temperature Range	-40° C to +85° C
nput LED	
Forward DC Current	40 mA
Reverse DC Voltage	2 V
Power Dissipation	100 mW
Output Phototransistor	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS		
Input IR LED								
V_{F}	Forward Voltage	1.2	2.0	2.3	V	I _F = 20 mA		
I_R	Reverse Current	-	-	100	μA	V _R = 2 V		
$\lambda_{ m P}$	Peak Emission Wavelength	-	650	-	nm	I _F = 20mA		
Output Phototransistor								
$V_{(BR)CE0}$	Collector Emitter Breakdown Voltage	30	-	-	V	I _C = 100 μA		
V _{(BR)ECO}	Emitter Collector Breakdown Voltage	5	-	-	٧	I _E = 100 μA		
I _{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0$		
Tr	Rise Time	-	300	-	μs	V _{CE} = 5 Volts ⁽³⁾		
Tf	Fall Time	_	300	_	us	I _C = 1 mA R _s = 20KO		

Coupled Characteristics

I _{C(ON)}	On-State Collector Current	0.25	-	-	mA	d = 0.030" (.76 mm) ⁽¹⁾⁽²⁾ I _F = 20 mA, V _{CE} = 5 V
V _{CE(SAT)}	Collector Emitter Saturation Voltage	-	-	0.4	٧	d = 0.030" (.76 mm) ⁽¹⁾⁽²⁾ I _C = 50 μA, I _F = 20 mA
I cx	Crosstalk Collector Current	-	-	0.05	mA	I _F = 20 mA, V _{CE} = 5 V No reflective test surface present

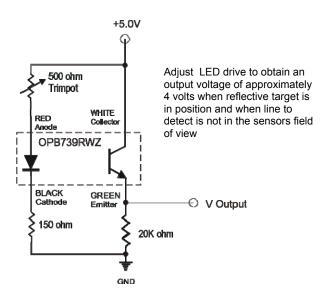
Notes:

- 1. "d" is the distance from the assembly's lens surface to the reflective surface.
- 2. Measured using 90% diffuse reflectance white test card as the reflecting surface.
- 3. Typical values by design. Rise and Fall times are not tested.
- 4. Methanol or Isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

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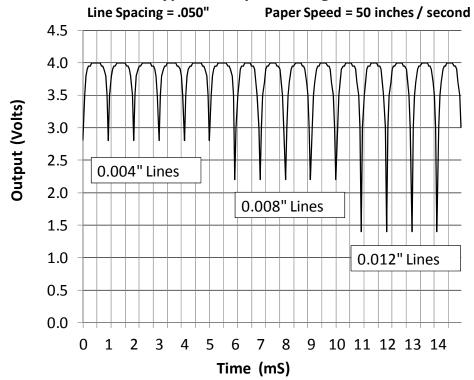
Typical Drive Circuit



Example reflective target with 0.004", 0.008", and .012" line widths spaced 0.050" apart



Typical Output Voltage vs Time



Reflective Line Reader Sensor Type OPB739RWZ



Typical Performance Curves

